



FMMT555

### 150V PNP MEDIUM POWER TRANSISTOR IN SOT23

### **Features**

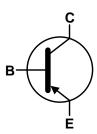
- $BV_{CEO} > -150V$
- I<sub>C</sub> = -1A High Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Pulse Current
- Complementary NPN Type: FMMT455
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

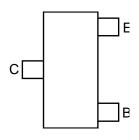
- Case: SOT23
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

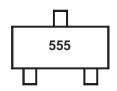
### **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT555TA	AEC-Q101	555	7	8	3,000
FMMT555TC	AEC-Q101	555	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## **Marking Information**



555 = Product Type Marking Code

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# **Absolute Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-160	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-150	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	Ісм	-2	Α
Base Current	I <sub>B</sub>	-200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)		$R_{\theta JL}$	197	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

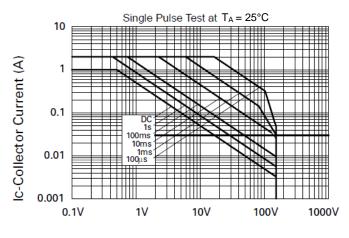
<sup>5.</sup> For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

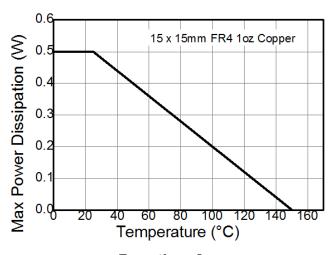


## **Thermal Characteristics and Derating Information**

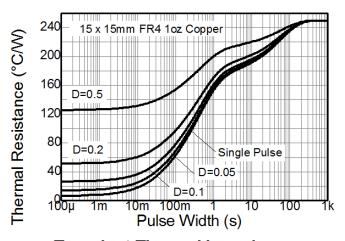


VCE - Collector Emitter Voltage (V)

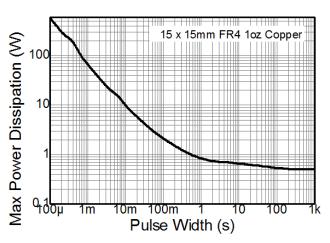
### Safe Operating Area



**Derating Curve** 



**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



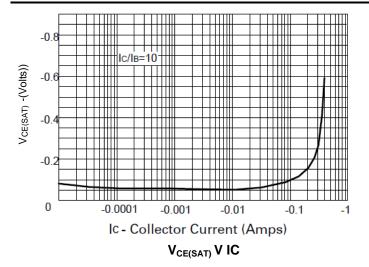
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

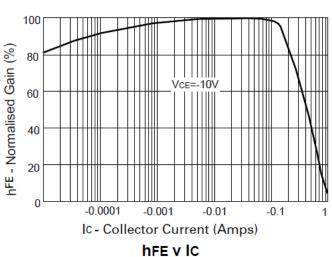
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-160	-290	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-150	-230	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.3	-	V	I <sub>E</sub> = -100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	-2	-100	nA	V <sub>CB</sub> = -140V
Collector-Emitter Cut-Off Current	Ices	_	-2	-100	nA	V <sub>CE</sub> = -140V
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	-1	-20	nA	V <sub>EB</sub> = -6V
Chatia Famurand Comment Transfer Datia (Nata 9)	L.	50	185	_	_	$I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	50	155	300	_	I <sub>C</sub> = -300mA, V <sub>CE</sub> = -10V
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(SAT)</sub>	_	-97	-300	mV	I <sub>C</sub> = - 100mA, I <sub>B</sub> = -10mA
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(SAT)</sub>	_	-0.79	-1	V	I <sub>C</sub> = - 100mA, I <sub>B</sub> = -10mA
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(ON)</sub>	_	-0.72	-1	V	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
Transition Frequency	f⊤	100	_	_	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -50mA, f = 100MHz
Output Capacitance	$C_{obo}$	_	_	10	pF	$V_{CB} = -10V$ , $f = 1MHz$

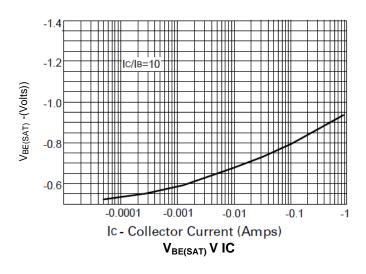
Note: 8. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s.$  Duty cycle  $\leq 2\%.$ 

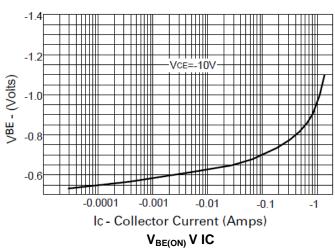


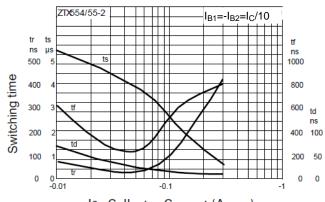
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)











Ic - Collector Current (Amps)

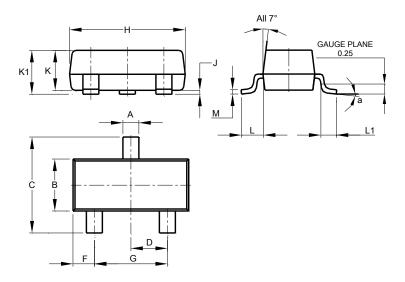
Switching Speeds



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

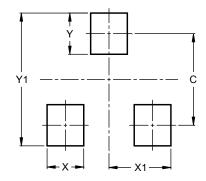


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
M	0.085	0.150	0.110		
а	0°	8°			
All	All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)		
С	2.0		
Х	0.8		
X1	1.35		
Υ	0.9		
V1	2.0		



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